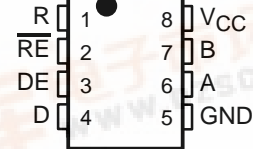


SN65LBC176A-EP DIFFERENTIAL BUS TRANSCEIVER

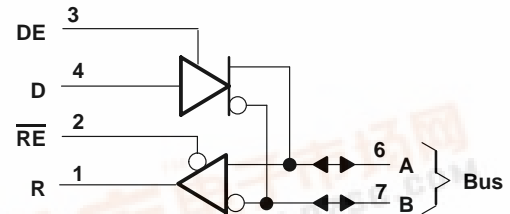
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- **Controlled Baseline**
 - One Assembly/Test Site, One Fabrication Site
- **Extended Temperature Performance of –40°C to 125°C**
- **Enhanced Diminishing Manufacturing Sources (DMS) Support**
- **Enhanced Product Change Notification**
- **Qualification Pedigree†**
- **High-Speed Low-Power LinBiCMOS™ Circuitry Designed for Signaling Rates‡ Up to 30 Mbps**
- **Bus-Pin ESD Protection Exceeds 12-kV HBM**
- **Compatible With ANSI Standard TIA/EIA-485-A and ISO 8482:1987(E)**
- **Low Skew**
- **Designed for Multipoint Transmission on Long Bus Lines in Noisy Environments**
- **Low Disabled Supply Current Requirements . . . 700 µA Maximum**
- **Common Mode Voltage Range of –7 V to 12 V**
- **Thermal-Shutdown Protection**
- **Driver Positive and Negative Current Limiting**
- **Open-Circuit Fail-Safe Receiver Design**
- **Receiver Input Sensitivity . . . ±200 mV Max**
- **Receiver Input Hysteresis . . . 50 mV Typ**
- **Glitch-Free Power-Up and Power-Down Protection**

D PackageP
(TOP VIEW)



logic diagram (positive logic)



Function Tables

DRIVER

INPUT D	ENABLE DE	OUTPUTS	
		A	B
H	H	H	L
L	H	L	H
X	L	Z	Z
Open	H	H	L

RECEIVER

DIFFERENTIAL INPUTS $V_A - V_B$	ENABLE \overline{RE}	OUTPUT R
$V_{ID} \geq 0.2 \text{ V}$	L	H
$-0.2 \text{ V} < V_{ID} < 0.2 \text{ V}$	L	?
$V_{ID} \leq -0.2 \text{ V}$	L	L
X	H	Z
Open	L	H

H = high level, L = low level, ? = indeterminate,
X = irrelevant, Z = high impedance (off)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

† Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

‡ Signaling rate by TIA/EIA-485-A definition restrict transition times to 30% of the bit length, and much higher signaling rates may be achieved without this requirement as displayed in the *TYPICAL CHARACTERISTICS* of this device.

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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



SN65LBC176A-EP

DIFFERENTIAL BUS TRANSCEIVER

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description

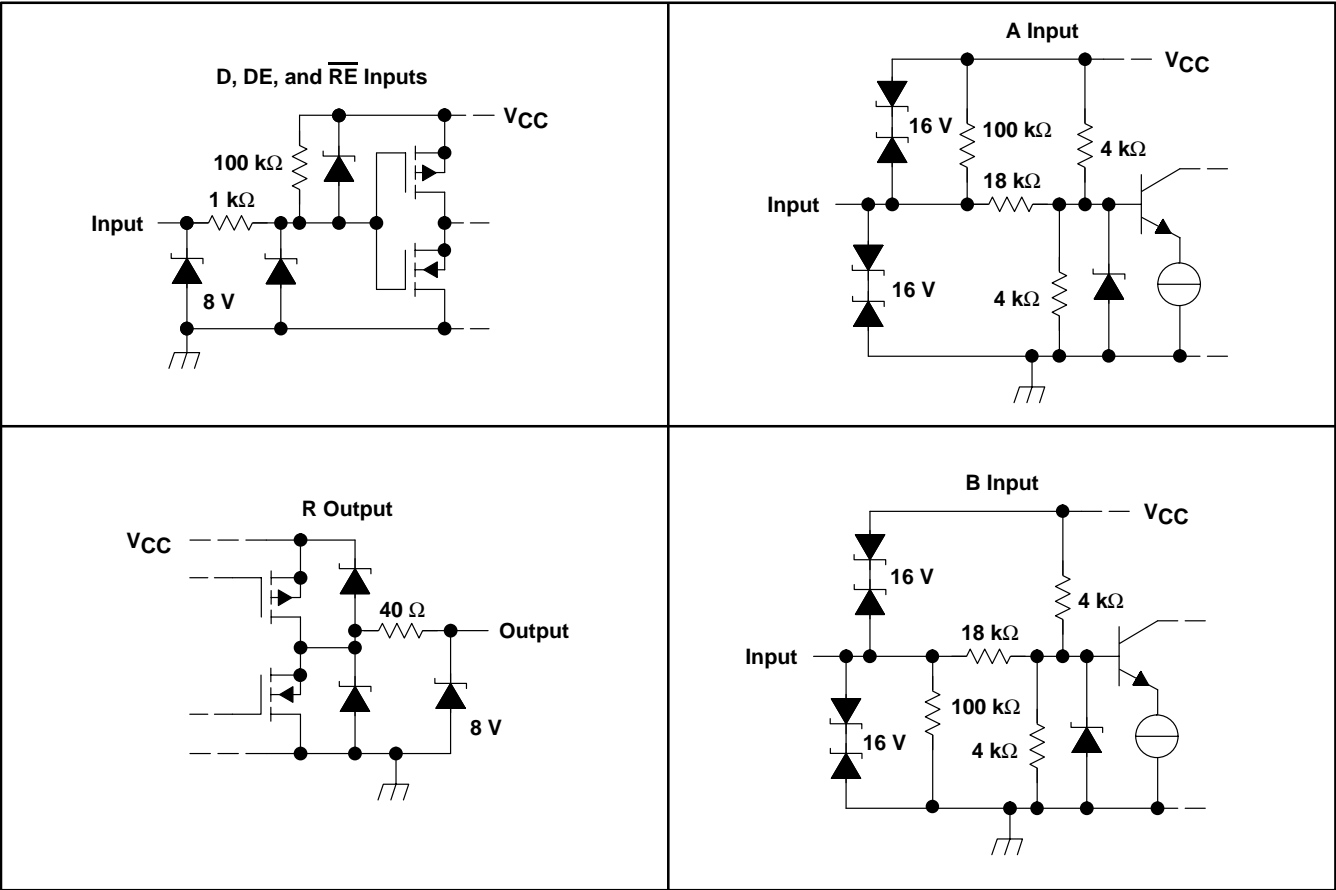
The SN65LBC176A-EP differential bus transceiver is a monolithic, integrated circuits designed for bidirectional data communication on multipoint bus-transmission lines. The SN65LBC176A-EP is designed for balanced transmission lines and is compatible with ANSI standard TIA/EIA-485-A and ISO 8482. The SN65LBC176A-EP offers improved switching performance over its predecessors without sacrificing significantly more power.

The SN65LBC176A-EP combines a 3-state, differential line driver and a differential input line receiver, both of which operate from a single 5-V power supply. The driver and receiver have active-high and active-low enables, respectively, which can externally connect together to function as a direction control. The driver differential outputs and the receiver differential inputs connect internally to form a differential input/output (I/O) bus port that is designed to offer minimum loading to the bus whenever the driver is disabled or $V_{CC} = 0$. This port features wide positive and negative common-mode voltage ranges, making the device suitable for party-line applications. Low device supply current can be achieved by disabling the driver and the receiver.

AVAILABLE OPTIONS

T _A	PACKAGE
	SMALL OUTLINE (D)
–40°C to 125°C	SN65LBC176AQDREP

schematics of inputs and outputs



SN65LBC176A-EP DIFFERENTIAL BUS TRANSCEIVER

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absolute maximum ratings†

Supply voltage, V_{CC} (see Note 1)	–0.3 V to 6 V
Voltage range at any bus terminal (A or B)	–10 V to 15 V
Input voltage, V_I (D, DE, R, or \overline{RE})	–0.3 V to $V_{CC} + 0.5$ V
Electrostatic discharge: Bus terminals and GND, Class 3, A: (see Note 2)	12 kV
Bus terminals and GND, Class 3, B: (see Note 2)	400 V
All terminals, Class 3, A:	4 kV
All terminals, Class 3, B:	400 V
Continuous total power dissipation (see Note 3)	See Dissipation Rating Table
Storage temperature range, T_{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. All voltage values, except differential I/O bus voltage, are with respect to network ground terminal.
 2. The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature.
 3. Tested in accordance with MIL–STD–883C, Method 3015.7

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR‡ ABOVE $T_A = 25^\circ\text{C}$	$T_A = 70^\circ\text{C}$ POWER RATING	$T_A = 85^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW

‡ This is the inverse of the junction-to-ambient thermal resistance when the board is mounted and with no air flow.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}		4.75	5	5.25	V
Voltage at any bus terminal (separately or common mode), V_I or V_{IC}		–7		12	V
High-level input voltage, V_{IH} (output recessive)	D, DE, and \overline{RE}	2		V_{CC}	V
Low-level input voltage, V_{IL} (output dominant)	D, DE, and \overline{RE}	0		0.8	V
Differential input voltage, V_{ID} (see Note 4)		–12§		12	V
High-level output current, I_{OH}	Driver	–60			mA
	Receiver	–8			
Low-level output current, I_{OL}	Driver			60	mA
	Receiver			8	
Operating free-air temperature, T_A	SN65LBC176A-EP	–40		125	°C

§ The algebraic convention, in which the least positive (most negative) limit is designated as minimum, is used in this data sheet.

NOTE 4: Differential input/output bus voltage is measured at the noninverting terminal A with respect to the inverting terminal B.

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DIFFERENTIAL BUS TRANSCEIVER

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driver electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V _{IK}	Input clamp voltage	I _I = −18 mA		−1.5	−0.8		V
V _{OD}	Differential output voltage	I _O = 0		1.5	4	6	V
		R _L = 54 Ω, See Figure 1		0.9	1.5	6	
		V _{test} = −7 V to 12 V, See Figure 2		0.9	1.5	6	V
Δ V _{OD}	Change in magnitude of differential output voltage	See Figures 1 and 2		−0.2		0.2	V
V _{OC(SS)}	Steady-state common-mode output voltage	See Figure 1		1.8	2.4	3	V
Δ V _{OC(SS)}	Change in steady-state common-mode output voltage†	See Figure 1		−0.2		0.2	V
I _{OZ}	High-impedance output current	See receiver input currents					
I _{IH}	High-level enable input current	V _I = 2 V		−100			μA
I _{IL}	Low-level enable input current	V _I = 0.8 V		−100			μA
I _{OS}	Short-circuit output current	−7 V ≤ V _O ≤ 12 V		−250	±70	250	mA
I _{CC}	Supply current	V _I = 0 or V _{CC} , No load	Receiver disabled and driver enabled	5		9	mA
			Receiver disabled and driver disabled	0.4		0.7	
			Receiver enabled and driver enabled	8.5		15	

† All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^\circ\text{C}$.

driver switching characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	SN65LBC176A-EP			UNIT
		MIN	TYP†	MAX	
t_{PLH} Propagation delay time, low-to-high-level output	$R_L = 54 \Omega$, $C_L = 50 \text{ pF}$, See Figure 3	2		12	ns
t_{PHL} Propagation delay time, high-to-low-level output		2		12	ns
$t_{sk(p)}$ Pulse skew ($ t_{PLH} - t_{PHL} $)				2	ns
t_r Differential output signal rise time		1.2		11	ns
t_f Differential output signal fall time		1.2		11	ns
t_{PZH} Propagation delay time, high-impedance-to-high-level output	$R_L = 110 \Omega$, See Figure 4			22	ns
t_{PZL} Propagation delay time, high-impedance-to-low-level output	$R_L = 110 \Omega$, See Figure 5			25	ns
t_{PHZ} Propagation delay time, high-level-to-high-impedance output	$R_L = 110 \Omega$, See Figure 4			22	ns
t_{PLZ} Propagation delay time, low-level-to-high-impedance output	$R_L = 110 \Omega$, See Figure 5			22	ns

† All typical values are at $V_{CC} = 5 \text{ V}$, $T_A = 25^\circ\text{C}$.

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receiver electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
V_{IT+} Positive-going input threshold voltage	$I_O = -8$ mA			0.2	V
V_{IT-} Negative-going input threshold voltage	$I_O = 8$ mA	-0.2			V
V_{hys} Hysteresis voltage ($V_{IT+} - V_{IT-}$)			50		mV
V_{IK} Enable-input clamp voltage	$I_I = -18$ mA	-1.5	-0.8		V
V_{OH} High-level output voltage	$V_{ID} = 200$ mV, $I_{OH} = -8$ mA, See Figure 6	4	4.9		V
V_{OL} Low-level output voltage	$V_{ID} = 200$ mV, $I_{OL} = 8$ mA, See Figure 6		0.1	0.8	V
I_{OZ} High-impedance-state output current	$V_O = 0$ to V_{CC}	-10		10	μ A
I_I Bus input current	$V_{IH} = 12$ V, $V_{CC} = 5$ V		0.4	1	mA
	$V_{IH} = 12$ V, $V_{CC} = 0$		0.5	1	
	$V_{IH} = -7$ V, $V_{CC} = 5$ V	-0.8	-0.4		
	$V_{IH} = -7$ V, $V_{CC} = 0$	-0.8	-0.3		
I_{IH} High-level enable-input current	$V_{IH} = 2$ V	-100			μ A
I_{IL} Low-level enable-input current	$V_{IL} = 0.8$ V	-100			μ A
I_{CC} Supply current	$V_I = 0$ or V_{CC} , No load	Receiver enabled and driver disabled	4	7	mA
		Receiver disabled and driver disabled	0.4	0.7	
		Receiver enabled and driver enabled	8.5	15	

† All typical values are at $V_{CC} = 5$ V, $T_A = 25^\circ\text{C}$.

receiver switching characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t_{PLH} Propagation delay time, output \uparrow	$V_{ID} = -1.5$ V to 1.5 V, See Figure 7	7		30	ns
t_{PHL} Propagation delay time, output \downarrow		7		30	ns
$t_{sk(p)}$ Pulse skew ($ t_{PHL} - t_{PLH} $)				6	ns
t_r Rise time, output	See Figure 7			5	ns
t_f Fall time, output				5	ns
t_{PZH} Output enable time to high level	$C_L = 10$ pF, See Figure 8			50	ns
t_{PZL} Output enable time to low level				50	ns
t_{PHZ} Output disable time from high level				60	ns
t_{PLZ} Output disable time from low level				40	ns

† All typical values are at $V_{CC} = 5$ V, $T_A = 25^\circ\text{C}$.

SN65LBC176A-EP DIFFERENTIAL BUS TRANSCEIVER

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PARAMETER MEASUREMENT INFORMATION

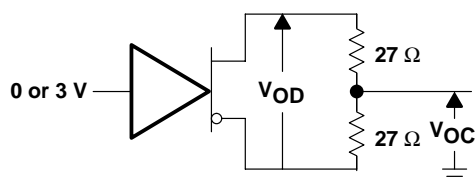


Figure 1. Driver V_{OD} and V_{OC}

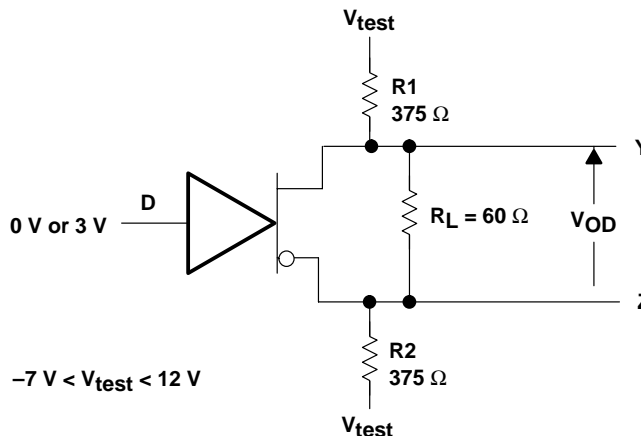
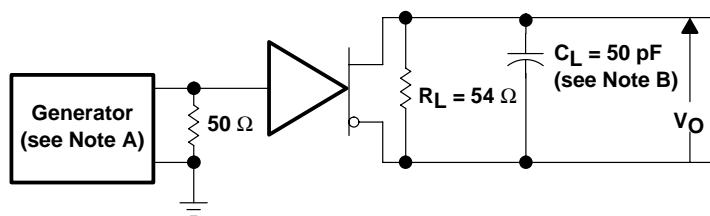
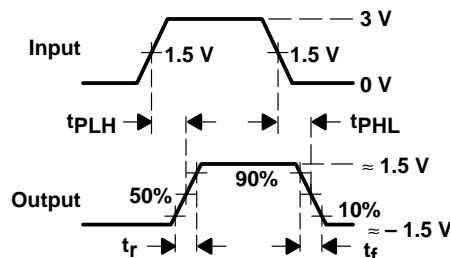


Figure 2. Driver V_{OD3}



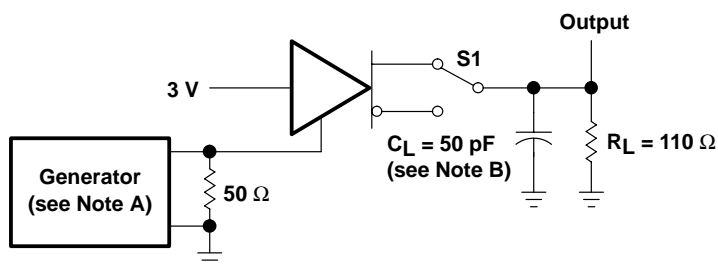
TEST CIRCUIT



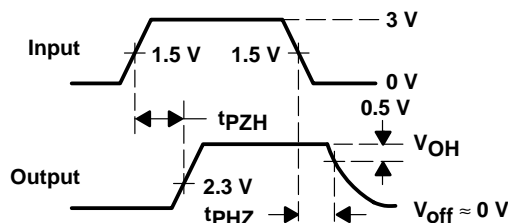
VOLTAGE WAVEFORMS

- NOTES: A. The input pulse is supplied by a generator having the following characteristics: $PRR \leq 1$ MHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.
B. C_L includes probe and jig capacitance.

Figure 3. Driver Test Circuit and Voltage Waveforms



TEST CIRCUIT

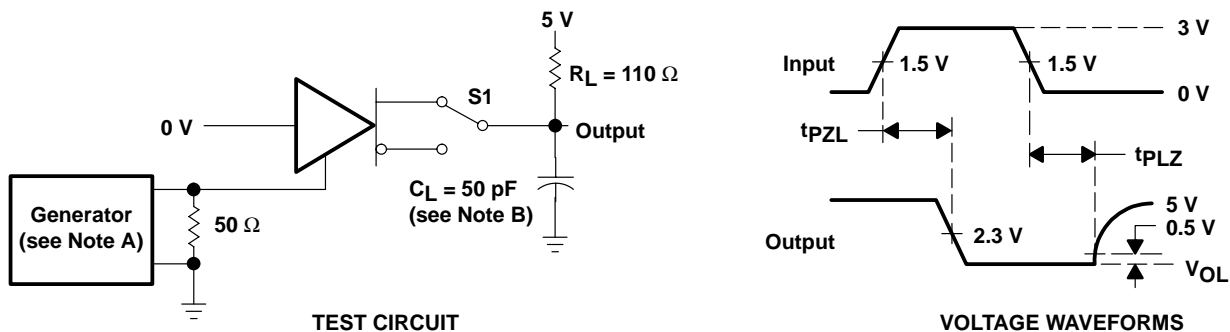


VOLTAGE WAVEFORMS

- NOTES: A. The input pulse is supplied by a generator having the following characteristics: $PRR \leq 1$ MHz, 50% duty cycle, $t_r \leq 6$ ns, $t_f \leq 6$ ns, $Z_O = 50 \Omega$.
B. C_L includes probe and jig capacitance.

Figure 4. Driver Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: $\text{PRR} \leq 1\ \text{MHz}$, 50% duty cycle, $t_r \leq 6\ \text{ns}$, $t_f \leq 6\ \text{ns}$, $Z_O = 50\ \Omega$.
B. C_L includes probe and jig capacitance.

Figure 5. Driver Test Circuit and Voltage Waveforms

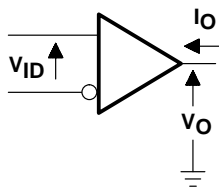
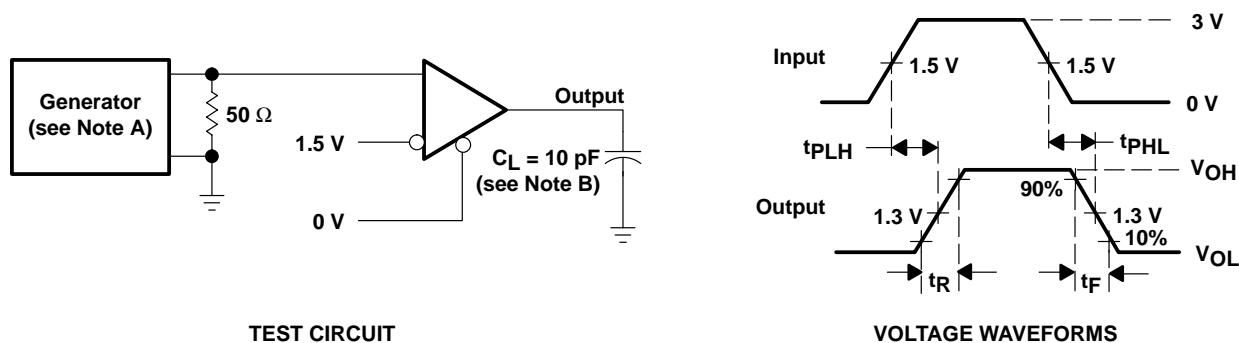


Figure 6. Receiver V_{OH} and V_{OL}



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: $\text{PRR} \leq 1\ \text{MHz}$, 50% duty cycle, $t_r \leq 6\ \text{ns}$, $t_f \leq 6\ \text{ns}$, $Z_O = 50\ \Omega$.
B. C_L includes probe and jig capacitance.

Figure 7. Receiver Test Circuit and Voltage Waveforms

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TEST CIRCUIT



B. C_L includes probe and jig capacitance.

Figure 8. Receiver Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS

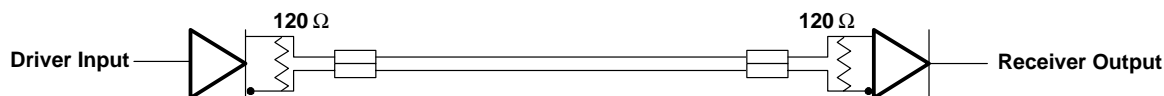
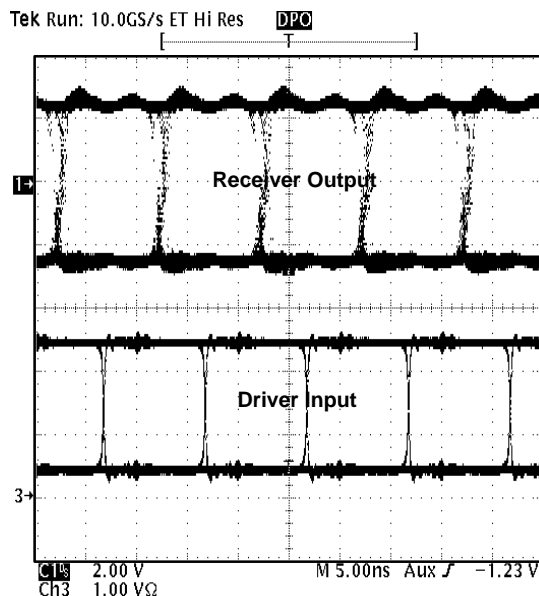


Figure 9. Typical Waveform of Non-Return-To-Zero (NRZ), Pseudorandom Binary Sequence (PRBS) Data at 100 Mbps Through 15m, of CAT 5 Unshielded Twisted Pair (UTP) Cable

TIA/EIA-485-A defines a maximum signaling rate as that in which the transition time of the voltage transition of a logic-state change remains less than or equal to 30% of the bit length. Transition times of greater length perform quite well, even though they do not meet the standard by definition.

SN65LBC176A-EP

DIFFERENTIAL BUS TRANSCEIVER

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TYPICAL CHARACTERISTICS

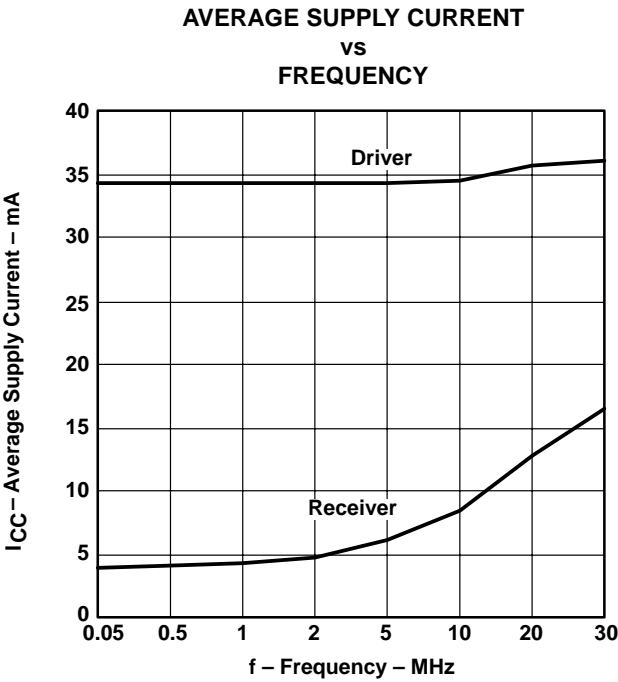


Figure 10

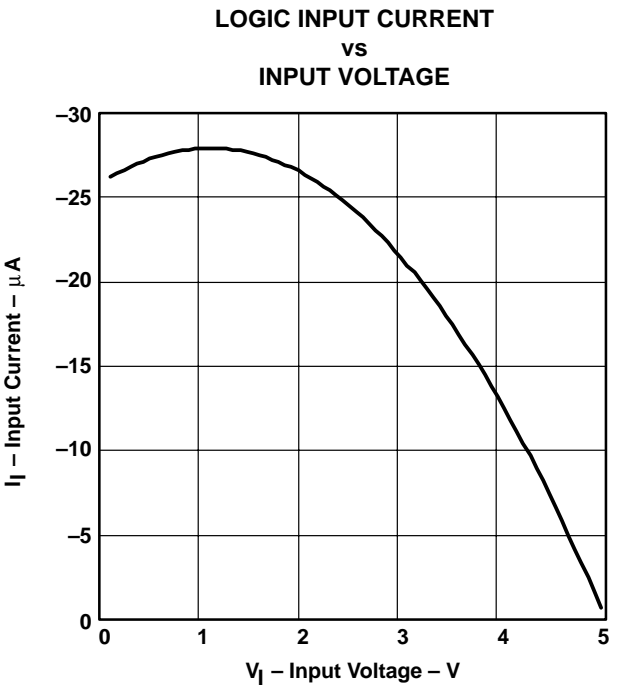


Figure 11

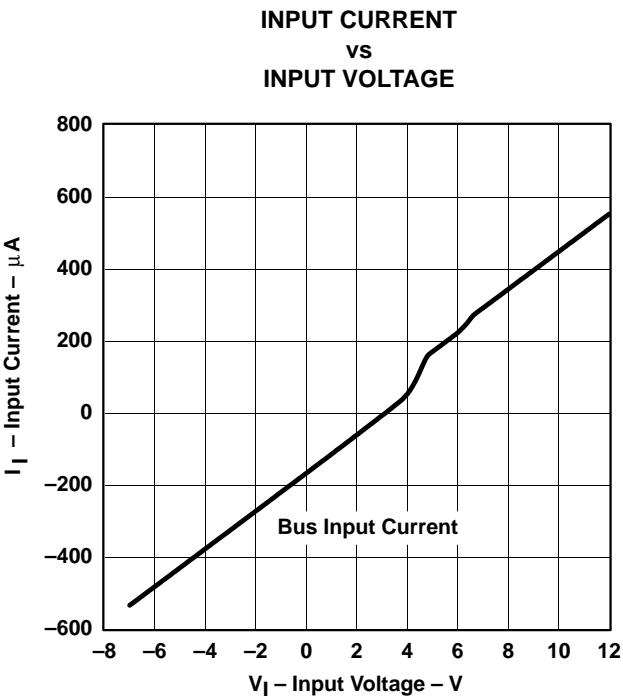


Figure 12

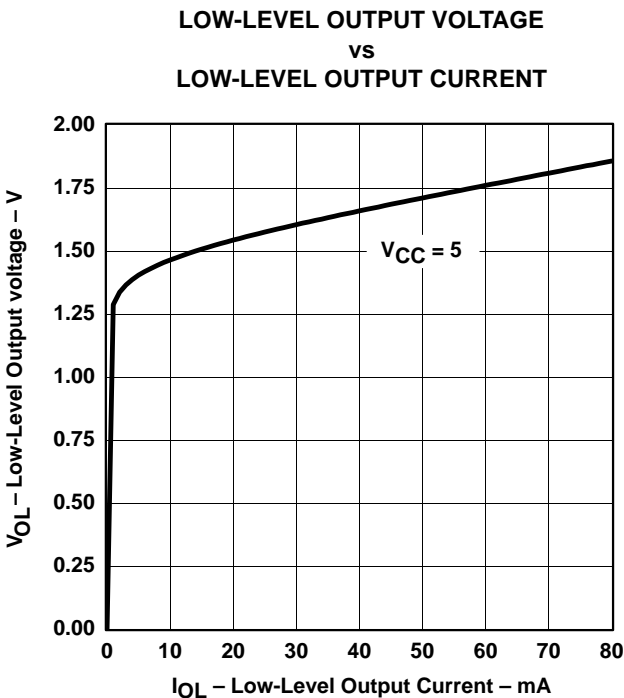


Figure 13

TYPICAL CHARACTERISTICS

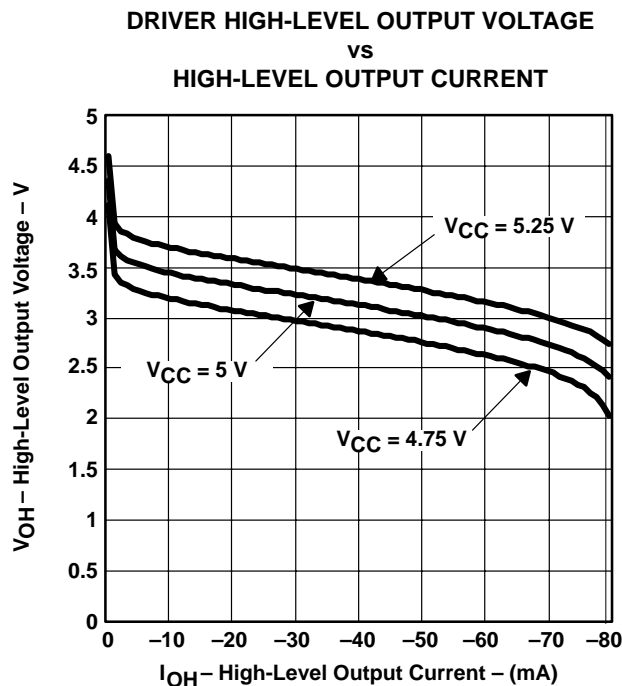


Figure 14

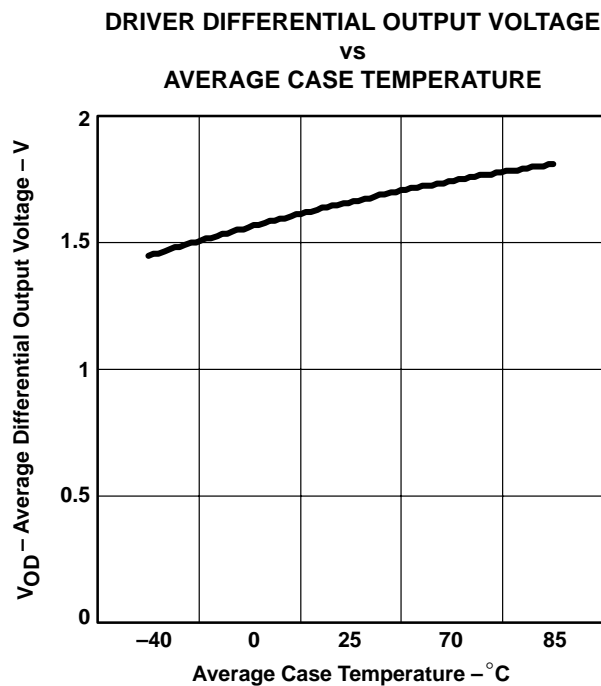


Figure 15

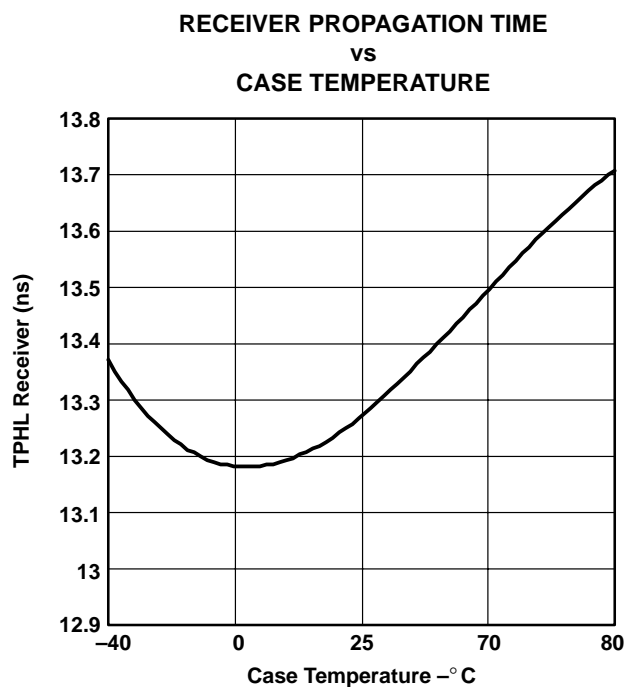


Figure 16

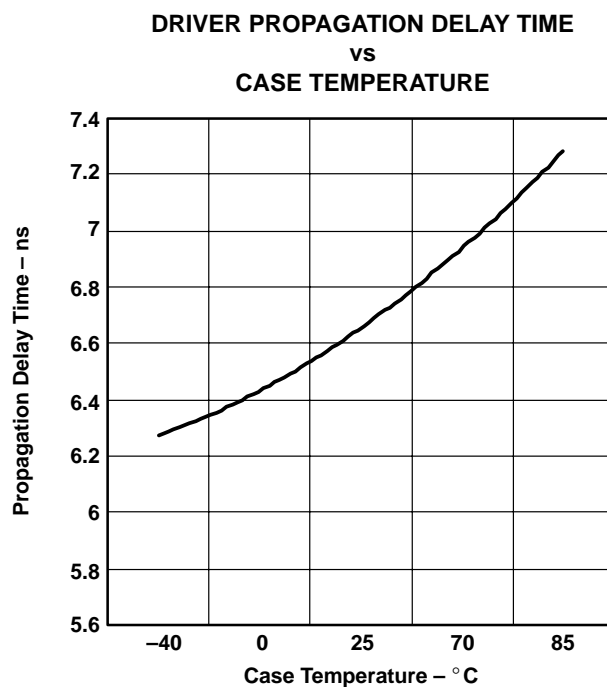


Figure 17

SN65LBC176A-EP
DIFFERENTIAL BUS TRANSCEIVER

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TYPICAL CHARACTERISTICS

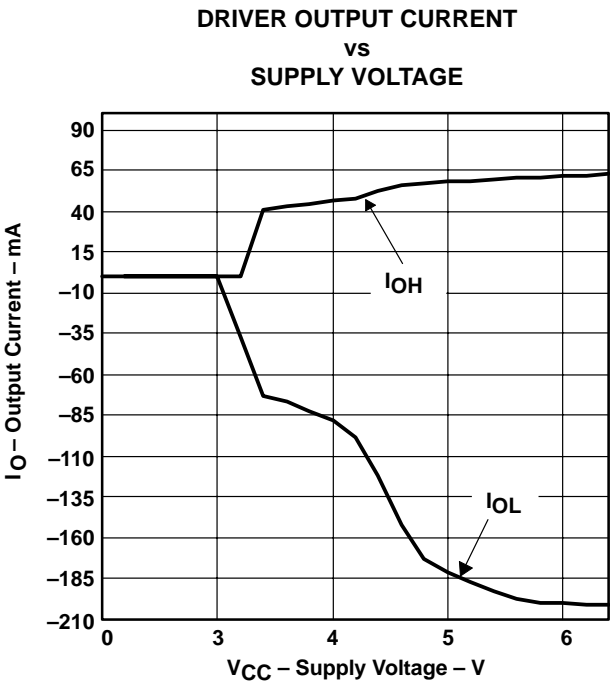


Figure 18

SN65LBC176A-EP DIFFERENTIAL BUS TRANSCEIVER

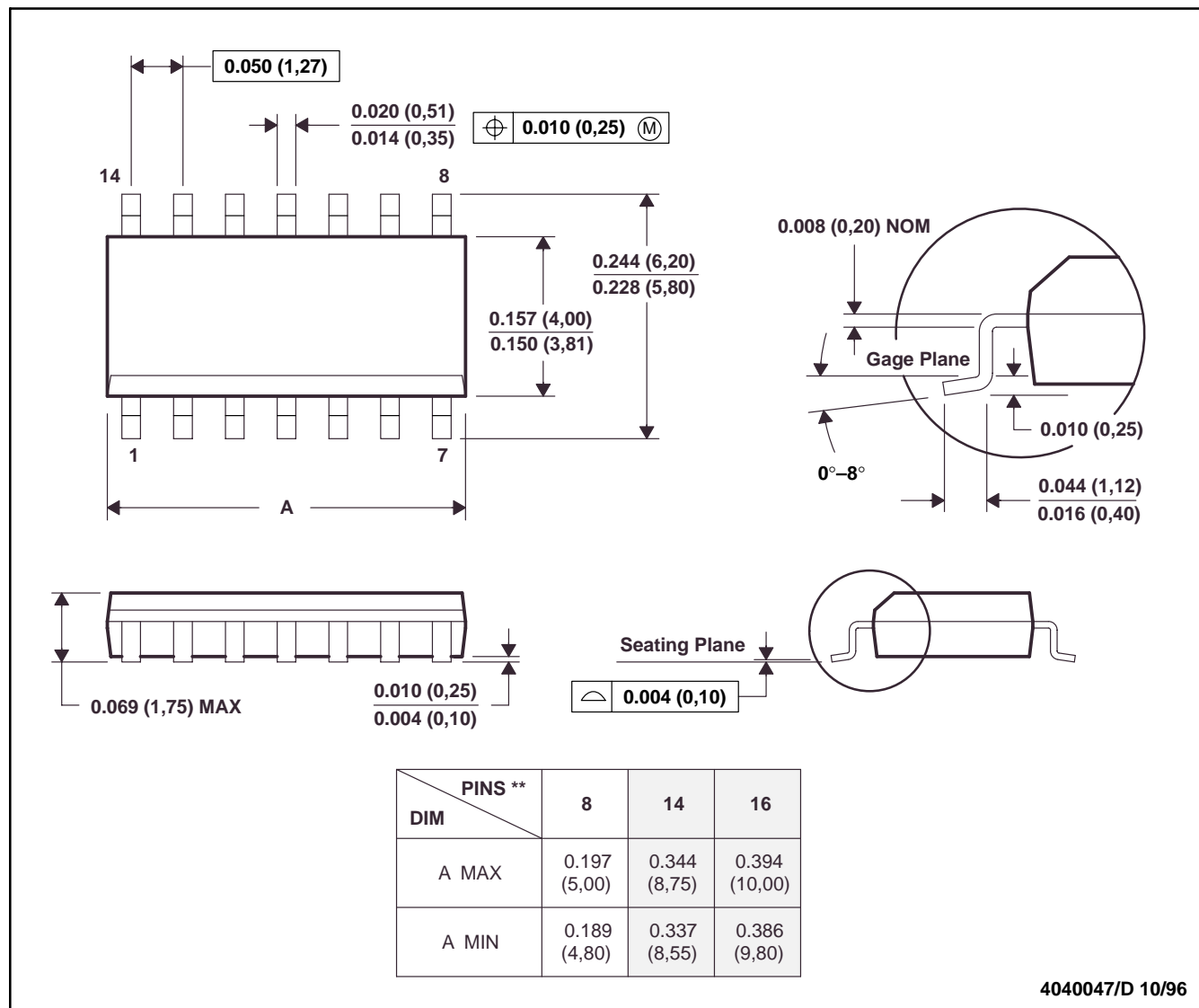
SGLS151 – DECEMBER 2002

MECHANICAL INFORMATION

D (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).
 - Falls within JEDEC MS-012

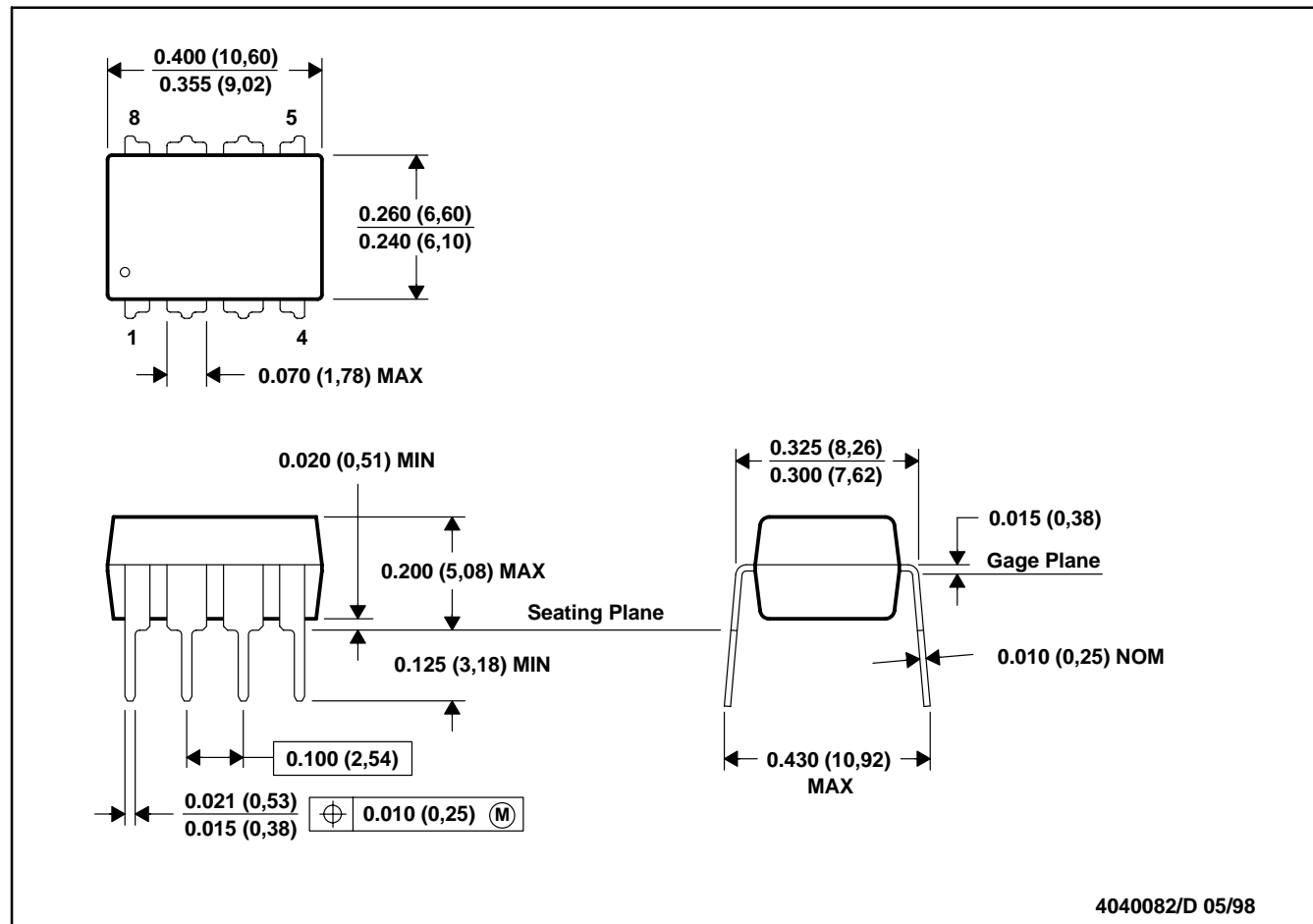
SN65LBC176A-EP DIFFERENTIAL BUS TRANSCEIVER

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MECHANICAL INFORMATION

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Falls within JEDEC MS-001

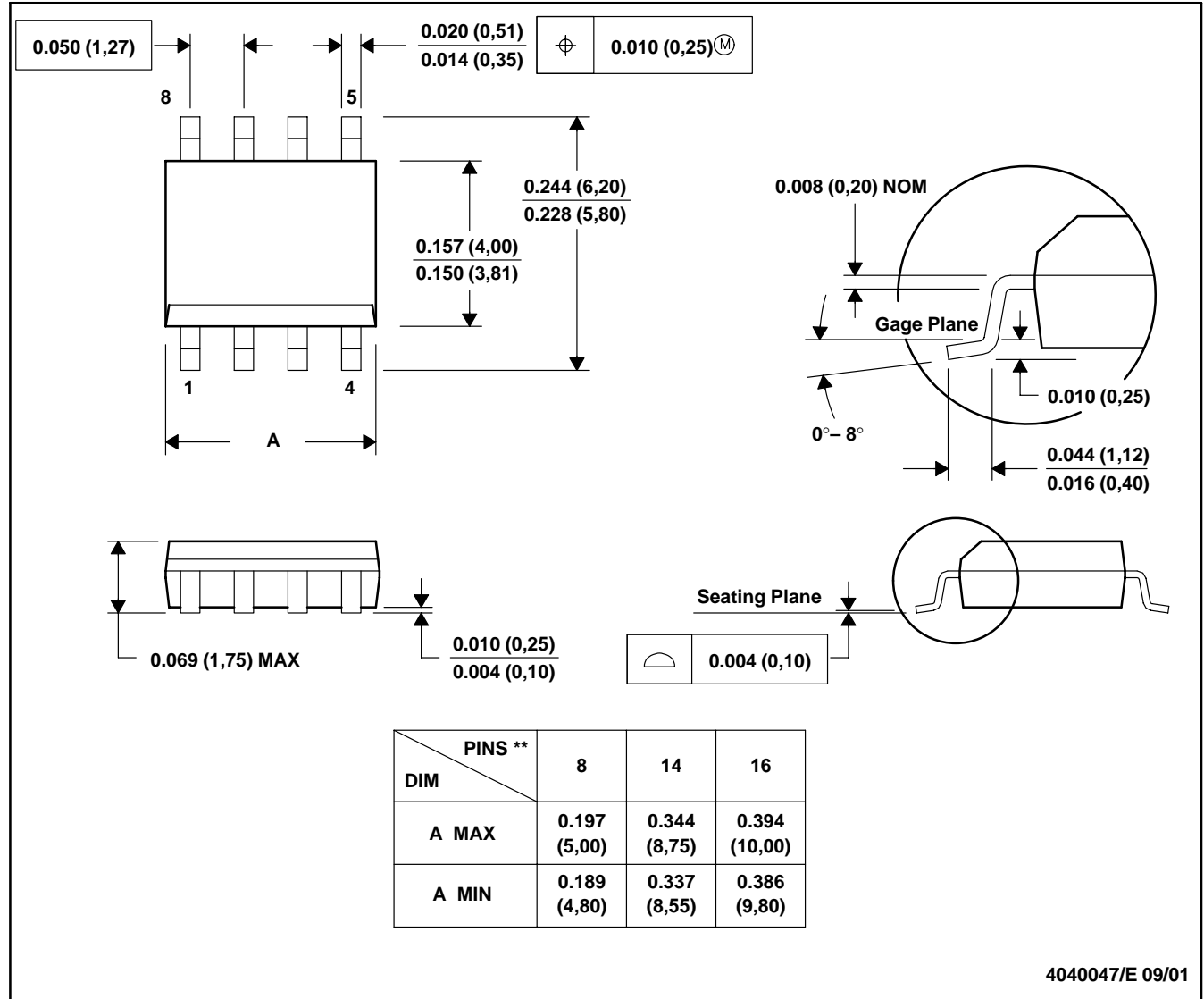
MECHANICAL DATA

MSOI002B – JANUARY 1995 – REVISED SEPTEMBER 2001

D (R-PDSO-G)**

PLASTIC SMALL-OUTLINE PACKAGE

8 PINS SHOWN



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).
 - D. Falls within JEDEC MS-012

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